

<b>Notice of References Cited</b>	Application/Control No. 10/078,473	Applicant(s)/Patent Under Reexamination KWON, HOKI	
	Examiner Dung (Michael) T Nguyen	Art Unit 2828	Page 1 of 1

**U.S. PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-			
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**FOREIGN PATENT DOCUMENTS**

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**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	B.T. McDermott et al., Appl. Phys. Lett.68,1386 (1996), "Growth and doping of GaAsSb via MOCVD for InP HBTs"
	V	M.J. Cherng et al., J. Electron. Mater. 13, 799 (1984), "GaAs1-xSbx growth by OMVPE"
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\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
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